L Number	Hits	Search Text	DB	Time stamp
93	5431	((438/586) or (438/587) or (438/598) or	USPAT;	2004/03/22
)	3431	(438/599) or (438/624)).CCLS.	US-PGPUB;	13:29
		(430/393/ OI (430/024/).cclb.	EPO; JPO;	13.23
			DERWENT;	
			IBM TDB	
94	1160	(((438/586) or (438/587) or (438/598) or	USPAT;	2004/03/22
73	1100	(438/599) or (438/624)).CCLS.) and	US-PGPUB;	13:33
		(contact adj hole)	EPO; JPO;	13.33
		(Contract adj note)	DERWENT;	
			IBM TDB	
95	646	((((438/586) or (438/587) or (438/598) or	USPAT;	2004/03/22
95	040	(((438/599) or (438/624)).CCLS.) and	US-PGPUB;	13:33
			EPO; JPO;	13.33
1		(contact adj hole)) and gate	DERWENT;	
			IBM TDB	
96	- 242	/////430/50C\ am /430/507\ am /430/500\	USPAT;	2004/03/22
96	- 242	(((((438/586) or (438/587) or (438/598)	1	
		or (438/599) or (438/624)).CCLS.) and	US-PGPUB;	13:33
		(contact adj hole)) and gate) and planariz\$5	EPO; JPO; DERWENT;	
		pranarizas	l	
97	100	///////////////////////////////////////	IBM_TDB USPAT;	2004/03/22
91	199	(((((438/586) or (438/587) or (438/598)		
		or (438/599) or (438/624)).CCLS.) and	US-PGPUB;	13:34
		(contact adj hole)) and gate) and	EPO; JPO;	
		(planariz\$5 same (dielectric or	DERWENT;	
	60	insulat\$3))	IBM_TDB	2004/02/22
99	62	(((((((438/586) or (438/587) or (438/598)	USPAT;	2004/03/22
		or (438/599) or (438/624)).CCLS.) and	US-PGPUB;	13:34
		(contact adj hole)) and gate) and	EPO; JPO;	
		(planariz\$5 same (dielectric or	DERWENT;	
		insulat\$3))) and (etch\$3 same rate same	IBM_TDB	
		(dielectric or insulat\$3))) and ((first		
		and second) same (dielectric or		
	e =	insulat\$3))		0004/00/00
98	65	((((((438/586) or (438/587) or (438/598)	USPAT;	2004/03/22
		or (438/599) or (438/624)).CCLS.) and	US-PGPUB;	13:37
		(contact adj hole)) and gate) and	EPO; JPO;	
		(planariz\$5 same (dielectric or	DERWENT;	1
	•	insulat\$3))) and (etch\$3 same rate same	IBM_TDB	1
100		(dielectric or insulat\$3))		0004 (00 (00
100	34	(((((((438/586) or (438/587) or (438/598)	USPAT;	2004/03/22
		or (438/599) or (438/624)).CCLS.) and	US-PGPUB;	13:37
,		(contact adj hole)) and gate) and	EPO; JPO;	
		(planariz\$5 same (dielectric or	DERWENT;	
		insulat\$3))) and (etch\$3 same rate same	IBM_TDB	
		(dielectric or insulat\$3))) and bpsg		

Search History 3/22/04 1:38:01 PM Page 1